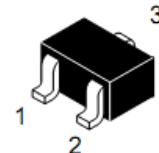


WPM3012

Single P-Channel, -30V, -3.1A, Power MOSFET

[Http://www.sh-willsemi.com](http://www.sh-willsemi.com)

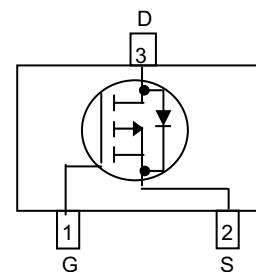
V_{DS} (V)	R_{DS(on)} (Ω)
-30	0.058@ V _{GS} =-10V
	0.080@ V _{GS} =-4.5V



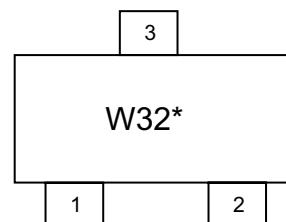
SOT-23

Descriptions

The WPM3012 is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. This device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product WPM3012 is Pb-free and Halogen-free.



Pin configuration (Top view)



W32= Device Code
* = Month (A~Z)

Marking

Features

- Trench Technology
- Supper high density cell design
- Excellent ON resistance for higher DC current
- Extremely Low Threshold Voltage
- Small package SOT-23

Applications

- Driver for Relay, Solenoid, Motor, LED etc.
- DC-DC converter circuit
- Power Switch
- Load Switch
- Charging

Order information

Device	Package	Shipping
WPM3012-3/TR	SOT-23	3000/Reel&Tape

Absolute Maximum ratings

Parameter	Symbol	10 S	Steady State	Unit
Drain-Source Voltage	V _{DS}	-30	V	
Gate-Source Voltage	V _{GS}	±20		
Continuous Drain Current ^a	T _A =25°C	I _D	-3.1	A
	T _A =70°C		-2.5	
Maximum Power Dissipation ^a	T _A =25°C	P _D	0.9	W
	T _A =70°C		0.6	
Continuous Drain Current ^b	T _A =25°C	I _D	-2.8	A
	T _A =70°C		-2.2	
Maximum Power Dissipation ^b	T _A =25°C	P _D	0.7	W
	T _A =70°C		0.5	
Pulsed Drain Current ^c	I _{DM}		-15	A
Operating Junction Temperature	T _J		150	°C
Lead Temperature	T _L		260	°C
Storage Temperature Range	T _{stg}		-55 to 150	°C

Thermal resistance ratings

Parameter	Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance ^a	t ≤ 10 s	R _{θJA}	105	°C/W
	Steady State		120	
Junction-to-Ambient Thermal Resistance ^b	t ≤ 10 s	R _{θJA}	130	°C/W
	Steady State		145	
Junction-to-Case Thermal Resistance	R _{θJC}	60	75	

a Surface mounted on FR-4 Board using 1 square inch pad size, 1oz copper

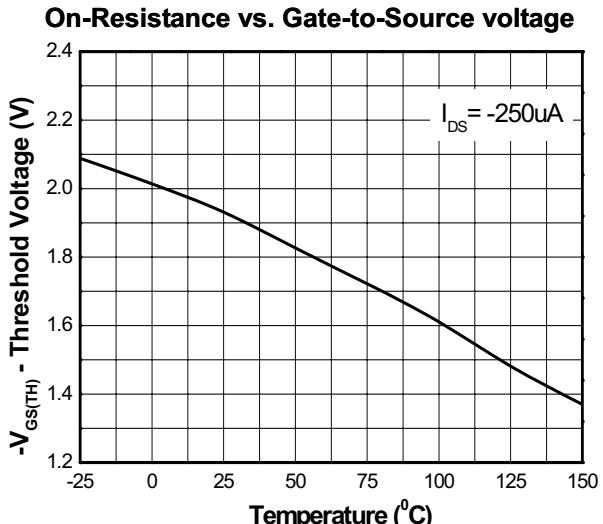
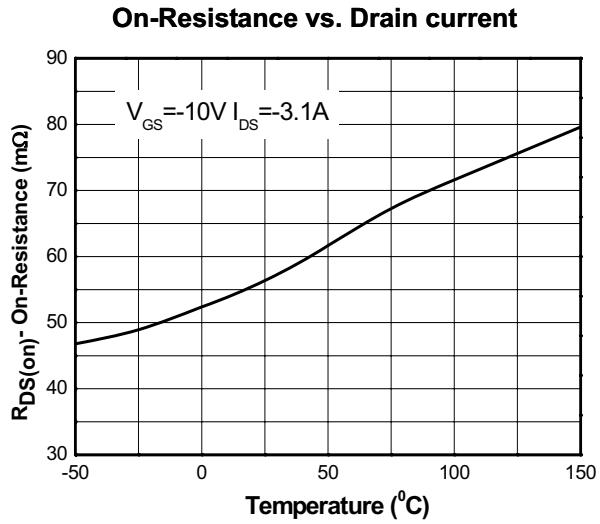
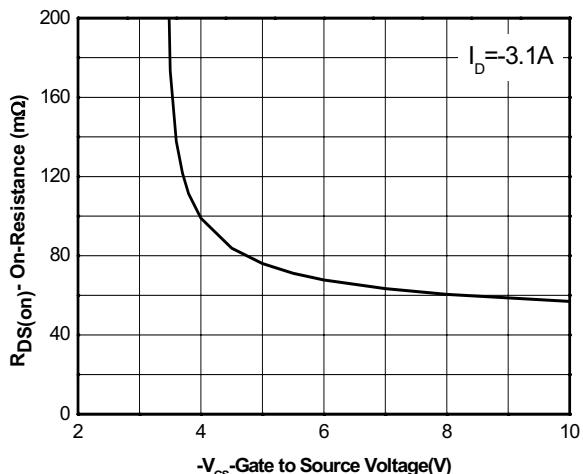
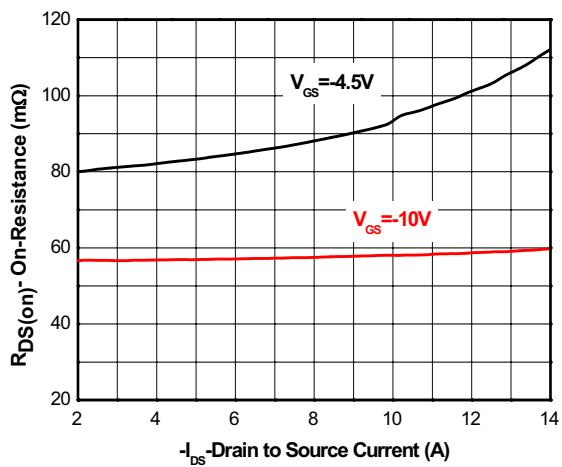
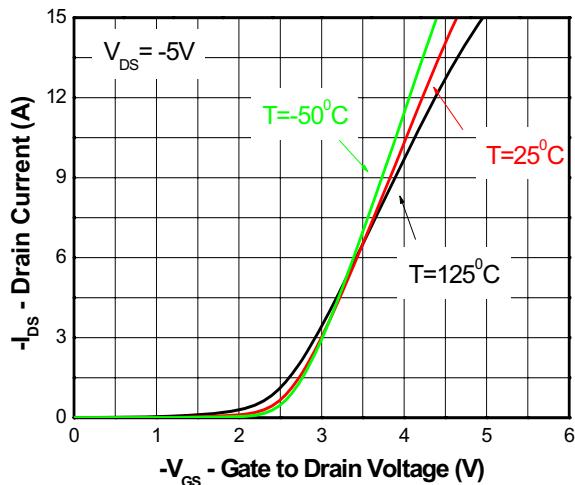
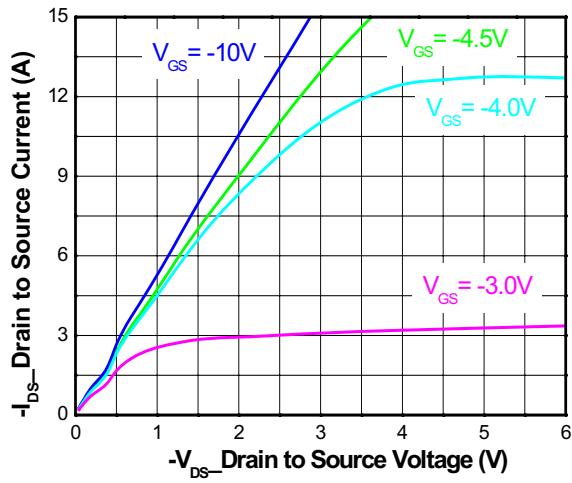
b Surface mounted on FR-4 board using minimum pad size, 1oz copper

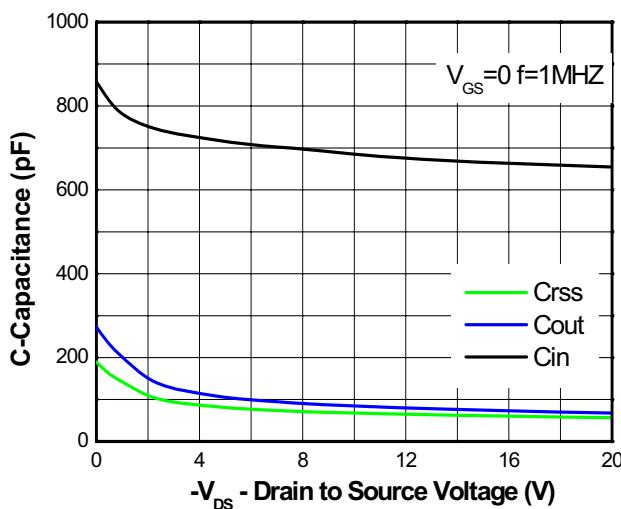
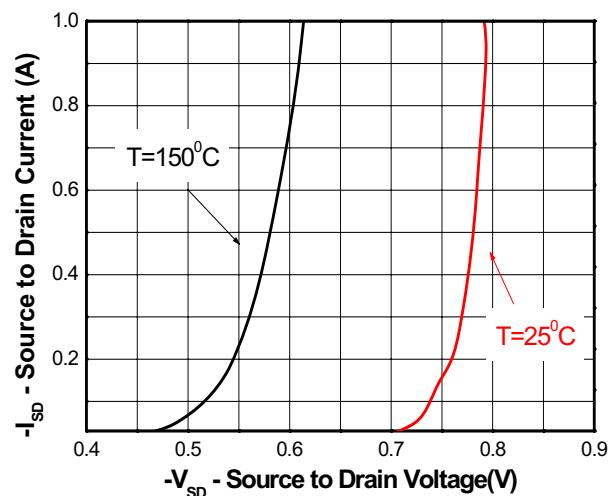
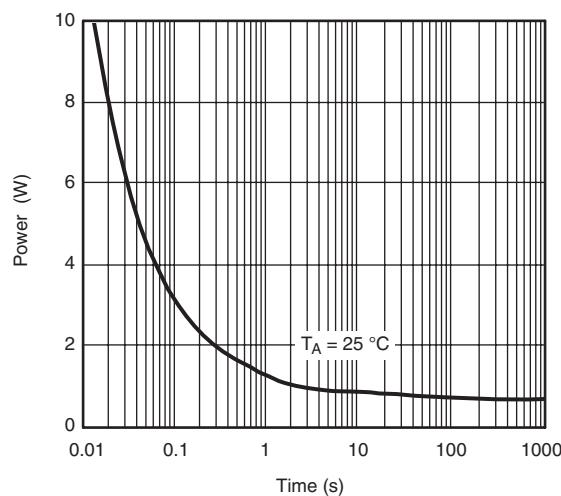
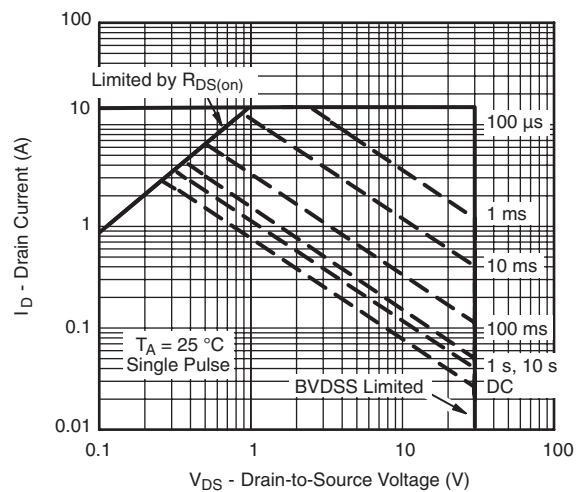
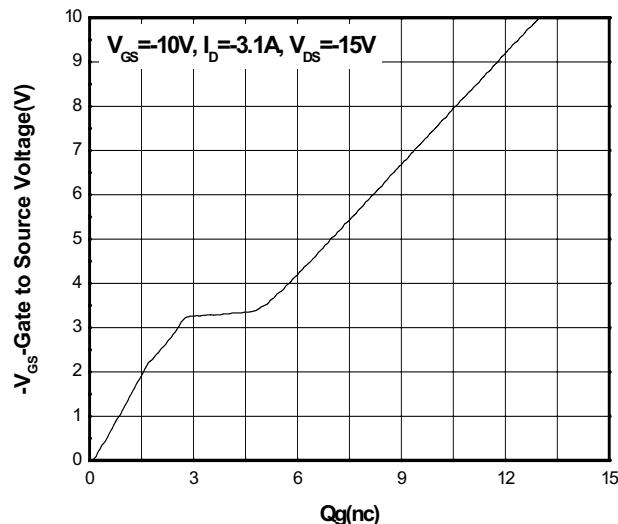
c Pulse width<380μs, Duty Cycle<2%

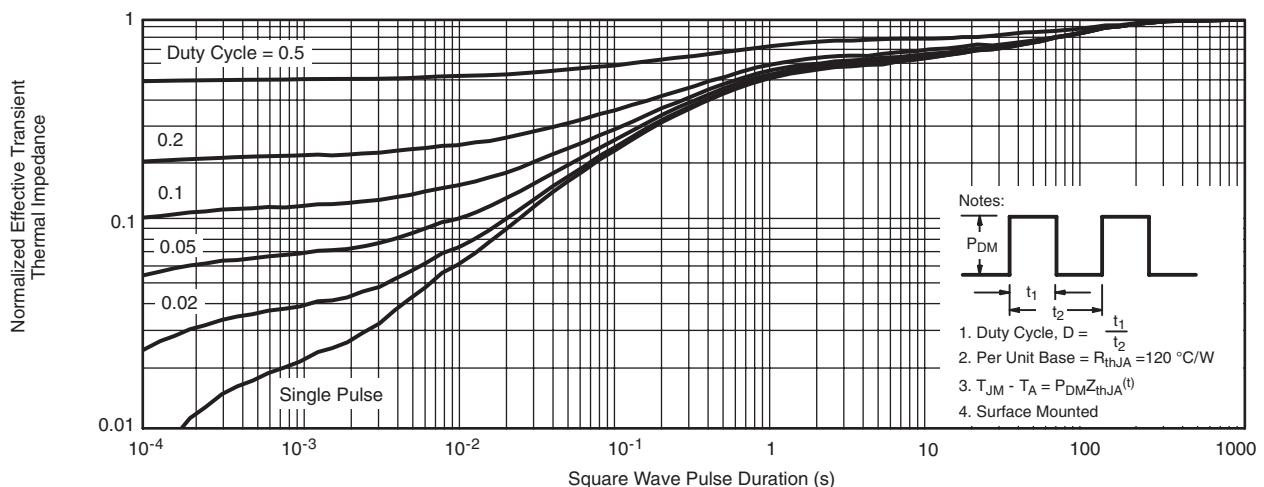
d Maximum junction temperature T_J=150°C.

Electronics Characteristics (Ta=25°C, unless otherwise noted)

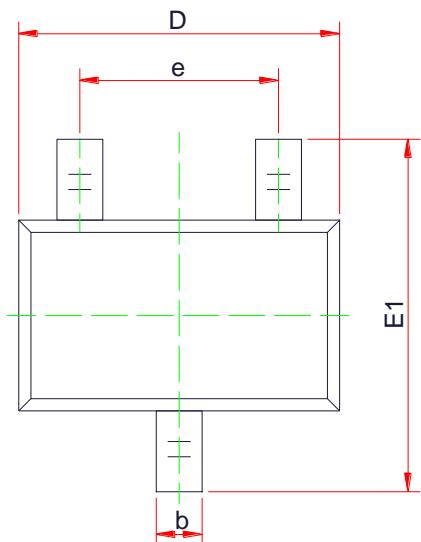
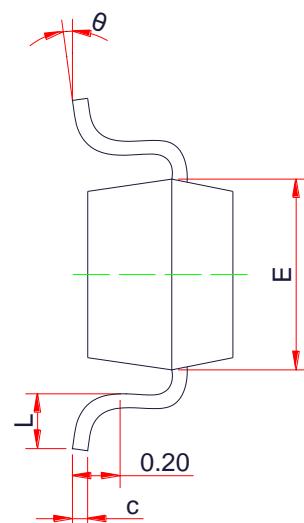
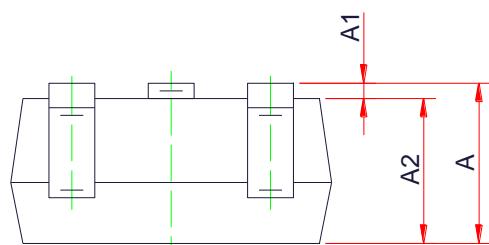
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0 \text{ V}, I_D = -250\mu\text{A}$	-30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -24\text{V}, V_{GS} = 0\text{V}$			-1	μA
Gate-to-source Leakage Current	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20\text{V}$			± 100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	$V_{GS} = V_{DS}, I_D = -250\mu\text{A}$	-1.5	-1.9	-2.5	V
Drain-to-source On-resistance ^{b, c}	$R_{DS(\text{on})}$	$V_{GS} = -10\text{V}, I_D = -3.1\text{A}$		58	68	$\text{m}\Omega$
		$V_{GS} = -4.5\text{V}, I_D = -2.8\text{A}$		80	95	
Forward Transconductance	g_{FS}	$V_{DS} = -5 \text{ V}, I_D = -5.0\text{A}$		8.2		s
CAPACITANCES, CHARGES						
Input Capacitance	C_{ISS}	$V_{GS} = 0 \text{ V},$ $f = 1.0 \text{ MHz},$ $V_{DS} = -20\text{V}$		654		pF
Output Capacitance	C_{OSS}			67		
Reverse Transfer Capacitance	C_{RSS}			56		
Total Gate Charge	$Q_{G(\text{TOT})}$	$V_{GS} = -10 \text{ V},$ $V_{DS} = -15\text{V},$ $I_D = -3.1\text{A}$		1.55		nC
Threshold Gate Charge	$Q_{G(\text{TH})}$			2.03		
Gate-to-Source Charge	Q_{GS}			3.15		
Gate-to-Drain Charge	Q_{GD}			12.9		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	$td(\text{ON})$	$V_{GS} = -10 \text{ V},$ $V_{DS} = -15 \text{ V},$ $R_L = 5\Omega,$ $R_G = 15 \Omega$		9.6		ns
Rise Time	tr			4.0		
Turn-Off Delay Time	$td(\text{OFF})$			34.8		
Fall Time	tf			7.2		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V_{SD}	$V_{GS} = 0 \text{ V}, I_S = -1.0\text{A}$		-0.8	-1.5	V

Typical Characteristics (Ta=25°C, unless otherwise noted)


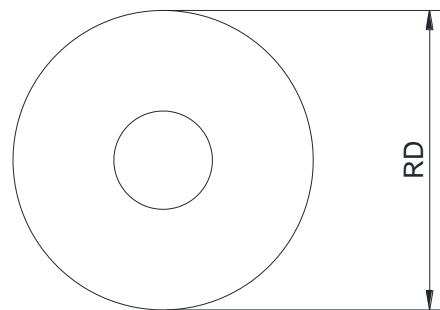
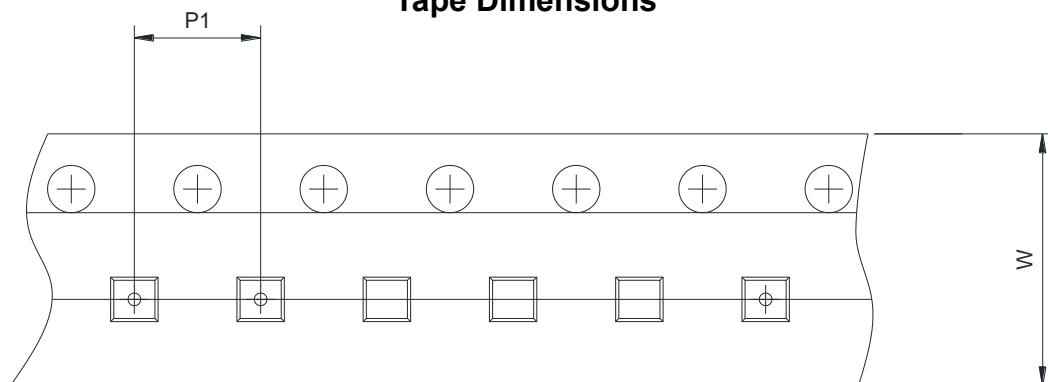
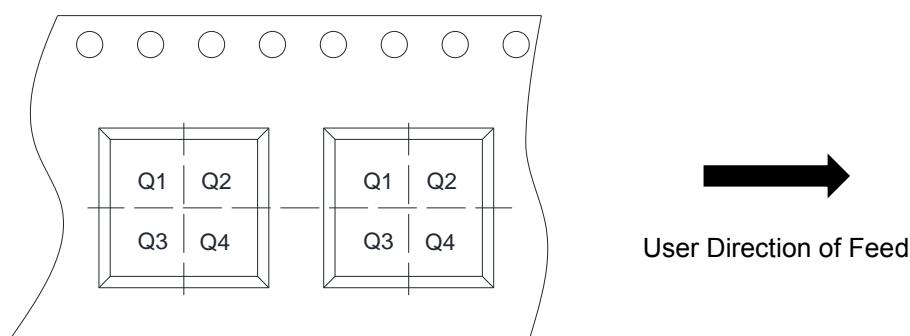

Capacitance

Body diode forward voltage

Single pulse power

Safe operating power

Gate Charge Characteristics



Transient thermal response (Junction-to-Ambient)

PACKAGE OUTLINE DIMENSIONS
SOT-323

TOP VIEW

SIDE VIEW

SIDE VIEW

Symbol	Dimensions in Millimeters		
	Min.	Typ.	Max.
A	0.80	0.95	1.10
A1	0.00	-	0.10
A2	0.80	0.90	1.00
b	0.20	0.30	0.40
c	0.05	0.10	0.15
D	1.90	2.05	2.20
E	1.15	1.25	1.25
E1	2.00	2.20	2.45
e	1.20	1.30	1.40
L	0.20	-	-
θ	6° Ref		

TAPE AND REEL INFORMATION
Reel Dimensions

Tape Dimensions

Quadrant Assignments For PIN1 Orientation In Tape


RD	Reel Dimension	<input checked="" type="checkbox"/> 7inch <input type="checkbox"/> 13inch
W	Overall width of the carrier tape	<input checked="" type="checkbox"/> 8mm <input type="checkbox"/> 12mm <input type="checkbox"/> 16mm
P1	Pitch between successive cavity centers	<input type="checkbox"/> 2mm <input checked="" type="checkbox"/> 4mm <input type="checkbox"/> 8mm
Pin1	Pin1 Quadrant	<input type="checkbox"/> Q1 <input type="checkbox"/> Q2 <input checked="" type="checkbox"/> Q3 <input type="checkbox"/> Q4

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